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direction.

CLAIMS

- 1. A ceramic heater comprising: a ceramic substrate; an insulating layer having volume resistivity higher than that of said ceramic substrate, being formed on at least a part of said ceramic substrate; and a resistance heating element formed on said insulating layer.
- The ceramic heater according to claim 1,
 wherein said ceramic substrate comprises a carbide ceramic or a nitride ceramic and said insulating layer comprises an oxide ceramic.
- 3. The ceramic heater according to claim 1 or 2,
 wherein the opposite side to the face where said
 resistance heating element is formed of said ceramic
 substrate is a heating face.
- 4. The ceramic heater according to any of claims 1 to 3, wherein the thickness of said insulating layer is from 0.1 to 1000 μm .
 - 5. The ceramic heater according to any of claims 1 to 3, wherein the volume resistivity of said insulating layer is not less than 10 times larger than the volume resistivity of said ceramic substrate.
 - 6. A ceramic heater comprising a ceramic substrate and a resistance heating element formed on a surface of said ceramic substrate,
 wherein said ceramic substrate is warped in one
- 7. The ceramic heater according to claim 6, wherein the warp amount of said ceramic substrate is from 10 to 100 μm .